

# BAV19W AT/ BAV20WAT / BAV21WAT

## FEATURES

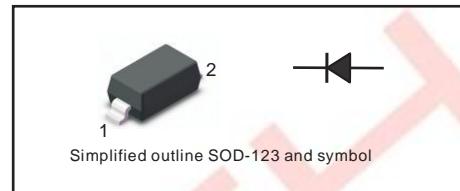
- ◆ For surface mounted applications
- ◆ Glass Passivated Chip Junction
- ◆ Fast reverse recovery time
- ◆ Ideal for automated placement
- ◆ Lead free in comply with EU RoHS 2011/65/EU directives

## PINNING

PIN	DESCRIPTION
1	Cathode
2	Anode

## MECHANICAL DATA

- ◆ Case: SOD-123



## Absolute Maximum Ratings at 25 °C

Parameter	Symbols	BAV19WAT	BAV20WAT	BAV21WAT	Units
Maximum Repetitive Peak Reverse Voltage	$V_{RRM}$	120	200	250	V
Maximum RMS voltage	$V_{RMS}$	100	150	200	V
Continuous Forward Current	$I_F$		250		mA
Repetitive Peak Forward Current	$I_{FRM}$			625	mA
Non-repetitive Peak Forward Surge Current at 1s at 1ms at 1 us	$I_{FSM}$		1 3 9		A
Total Power Dissipation	$P_{tot}$		500		mW
Operating and Storage Temperature Range	$T_j, T_{stg}$		-55 ~ +150		°C

## Characteristics at $T_a = 25^\circ\text{C}$

Parameter	Symbols	BAV19WAT	BAV20WAT	BAV21WAT	Units
Reverse Breakdown Voltage at $I_R=100\mu\text{A}$	$V_{(BR)R}$	120	200	250	V
Maximum Forward Voltage at 100 mA at 200 mA	$V_F$		1.00 1.25		V
Maximum DC Reverse Current at Rated DC Blocking Voltage $T_a = 25^\circ\text{C}$ $T_a = 150^\circ\text{C}$	$I_R$		0.1 100		μA
Typical Junction Capacitance at $V_R=4\text{V}$ , $f=1\text{MHz}$	$C_J$		5		pF
Maximum Reverse Recovery Time	$t_{rr}$		50		ns

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## Typical Characteristics Curves

Fig.1 Forward Current Derating Curve

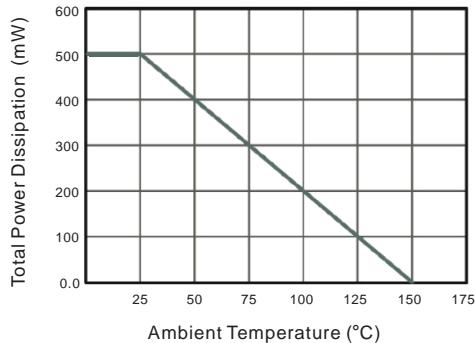


Fig.2 Typical Reverse Characteristics

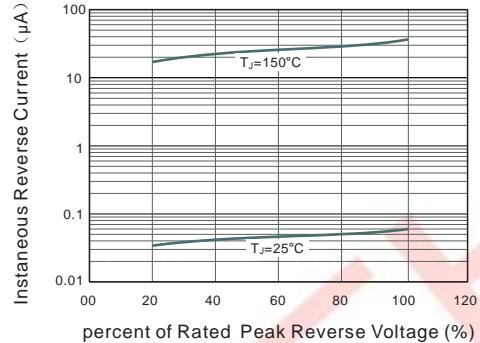


Fig.3 Typical Instantaneous Forward Characteristics

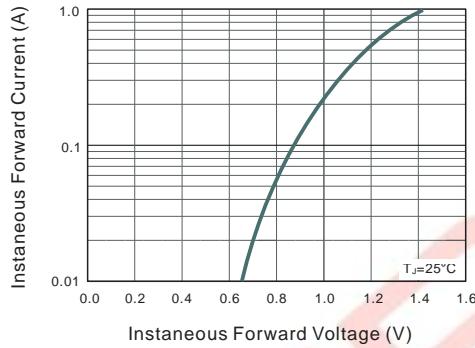
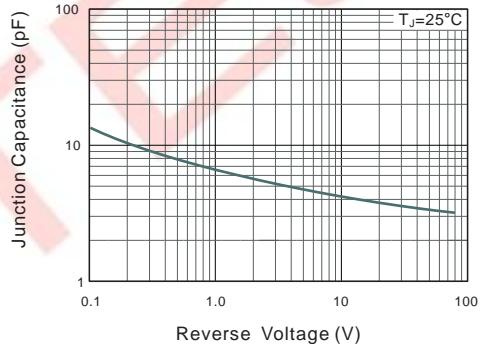


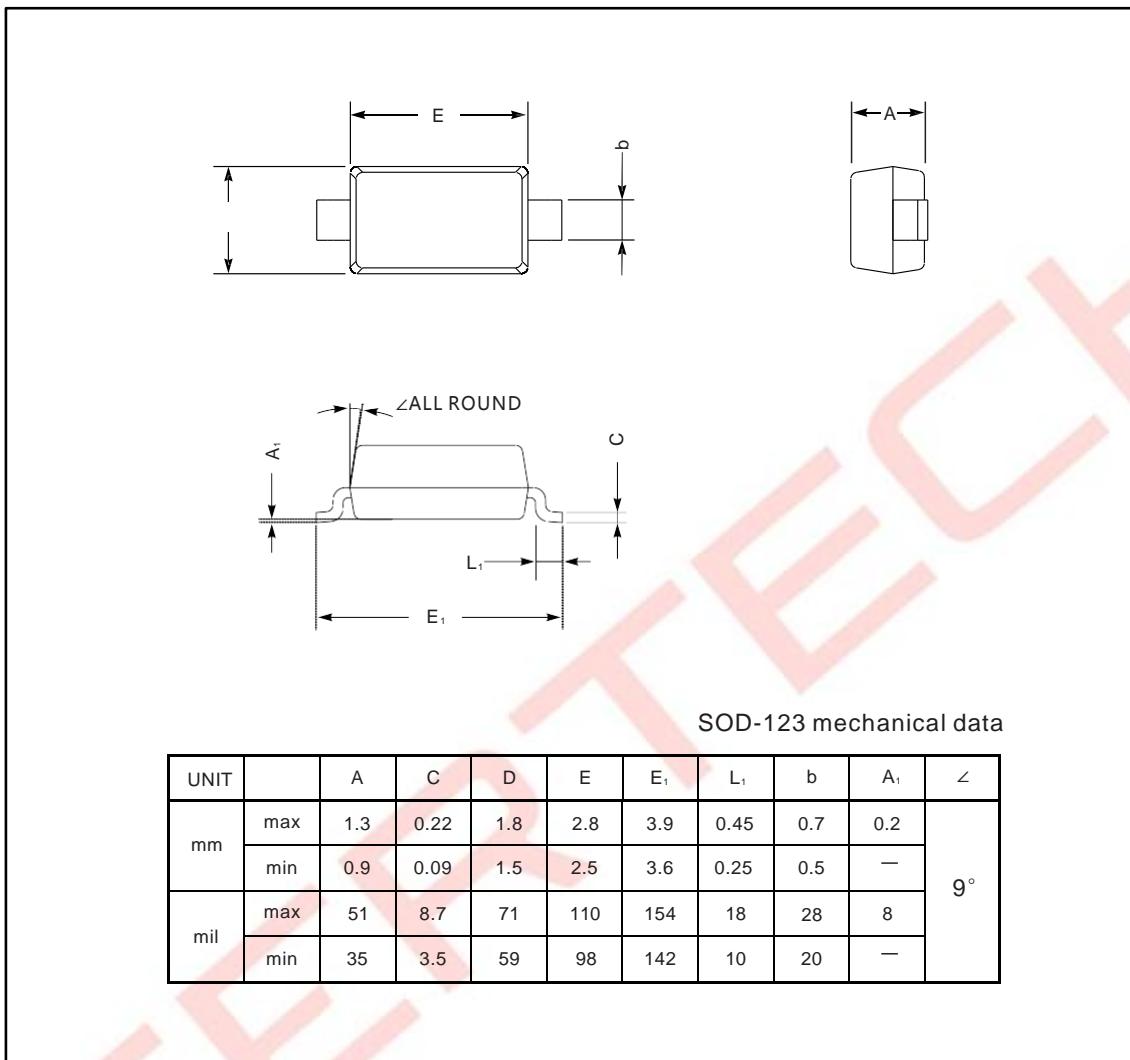
Fig.4 Typical Junction Capacitance



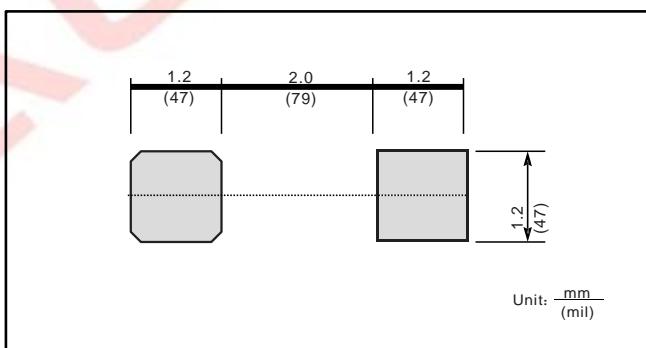
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## Package outline

SOD-123



### The recommended mounting pad size



### Marking

Type number	Marking code
BAV19WAT	A8
BAV20WAT	T2
BAV21WAT	T3